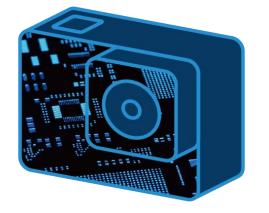
Action Camera

Solution Proposal by Toshiba



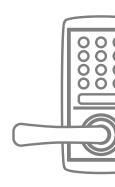






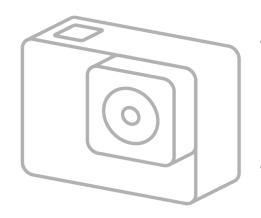




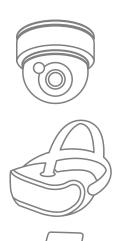






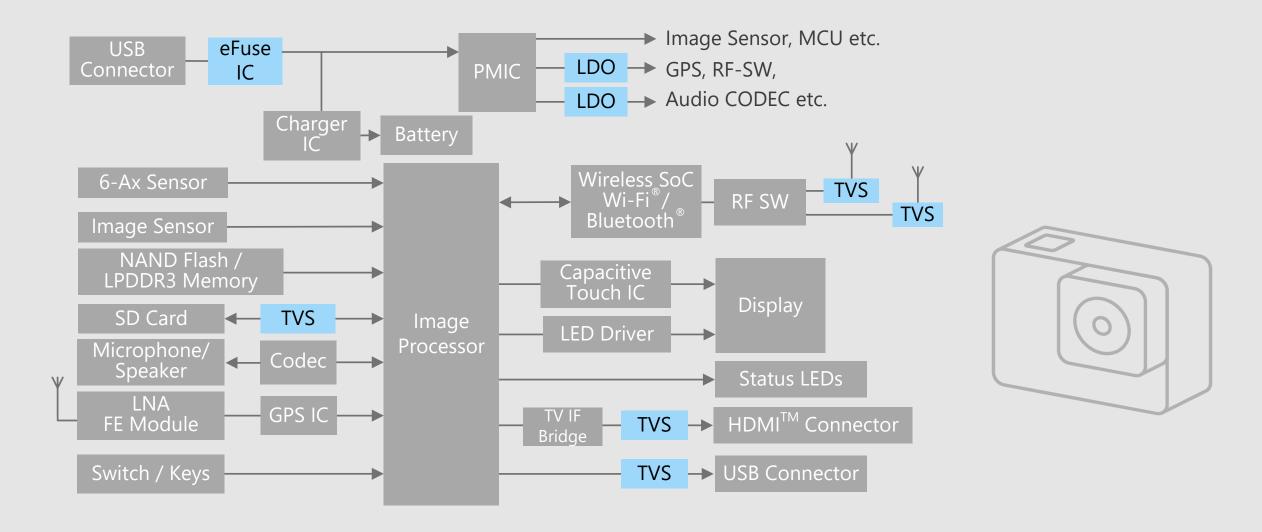


Toshiba Electronic Devices & Storage Corporation provides comprehensive device solutions to customers developing new products by applying its thorough understanding of the systems acquired through the analysis of basic product designs.



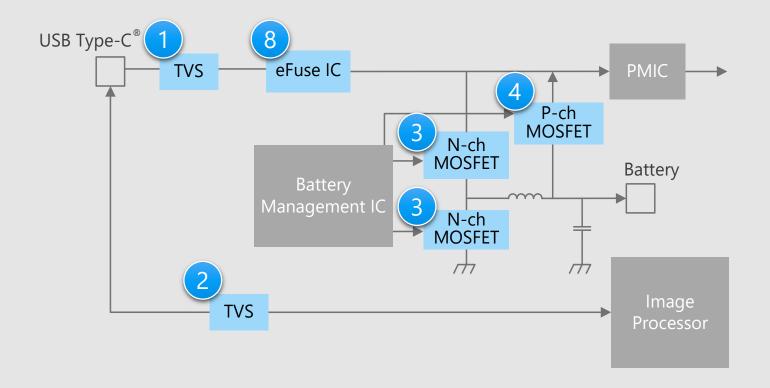
Block Diagram

Action Camera Overall block diagram



Action Camera Detail of USB connector peripheral unit

Battery and USB unit



X Click on the number in the circuit diagram to jump to the detailed description page

Criteria for device selection

- Since the power line is susceptible to induced lightning, ESD protection devices are required to have higher tolerances.
- Lower capacitance ESD protection device is required not to affect the transmission of high speed signals on data lines.
- Lower on-resistance MOSFET is required to improve energy efficiency.
- Circuit board area can be reduced by adopting compact package products.

- TVS diode with compact package and high ESD tolerance
 - Standard capacitance TVS diode
- TVS diode with compact package and low capacitance
 - Low capacitance TVS diode
- MOSFET with compact package and low on-resistance Small signal MOSFET (N-ch)
- **MOSFET** with compact package and low on-resistance Small signal MOSFET (P-ch)
- **Robust protection function** Electronic fuse (eFuse IC)

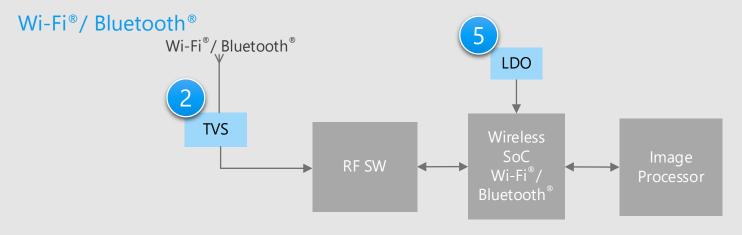






Action Camera Detail of RF unit

RF unit



RF unit **GPS** LDO LDO **GPS** LNA EEM **GPS IC**

X Click on the number in the circuit diagram to jump to the detailed description page

Criteria for device selection

- Lower capacitance ESD protection devices are required not to affect the transmission of high speed signals from antenna.
- LDO regulator having a high current driving capability for transmitting Wi-Fi® / Bluetooth® and having a low dropout characteristic is required for efficient voltage conversion.
- To realize compact size and efficient voltage conversion, Low drop-out characteristic is required to LDO regulator.
- Compact packages can reduce the circuit board area.

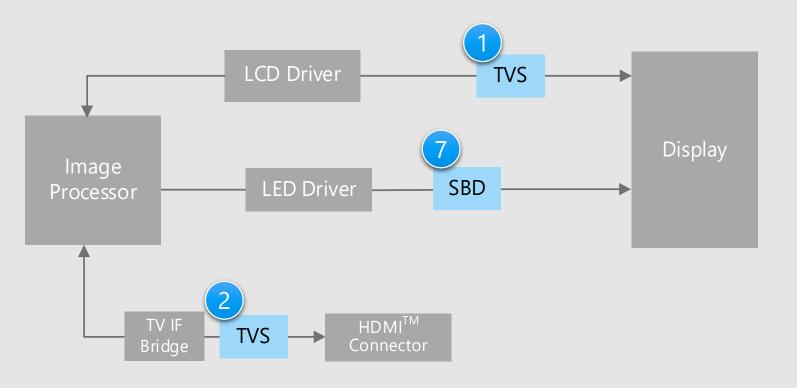
Proposals from Toshiba

- TVS diode with compact package and low capacitance
 - Low capacitance TVS diode
- LDO regulator with compact package and capable of applying a large current High current LDO regulator
- LDO Regulator with compact package and low dropout characteristics

Small current LDO regulator

Action Camera Detail of display peripheral unit

Display unit



X Click on the number in the circuit diagram to jump to the detailed description page

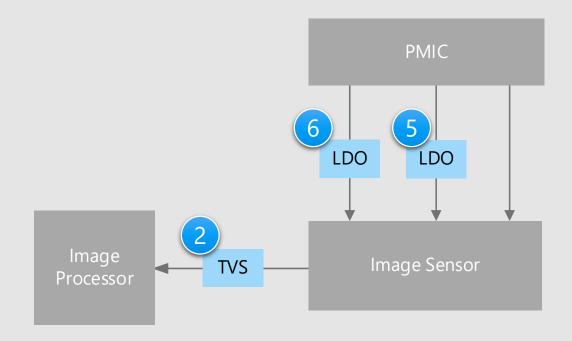
Criteria for device selection

- Low V_F characteristics are required for efficient power supply.
- Lower capacitance ESD protection device is required not to affect the transmission of high speed signals on the data lines.
- Compact packages can reduce the circuit board area

- TVS diode with compact package and high ESD tolerance
 Standard capacitance TVS diode
- TVS diode with compact package and low capacitance
 Low capacitance TVS diode
- SBD with compact package and low V_F characteristics
 Schottky barrier diode (SBD)

Action Camera Detail of camera peripheral unit

Camera unit



X Click on the number in the circuit diagram to jump to the detailed description page

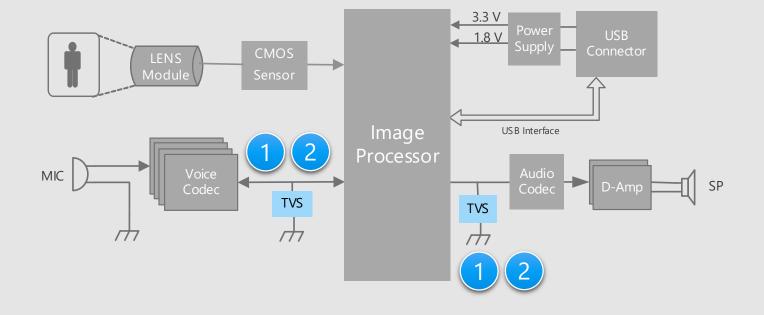
Criteria for device selection

- LDO regulator with low current consumption and low drop-out characteristics is required to last battery long.
- LDO regulator with low drop-out characteristic is required to realize large current drive capability and efficient voltage conversion.
- Lower capacitance ESD protection device is required not to affect the transmission of high speed signals on a data line.
- Circuit board area can be reduced by adopting compact packages.

- TVS diode with compact package and high ESD tolerance
 - Low capacitance TVS diode
 - LDO regulator with compact package and capable of applying a large current
 High current LDO regulator
- LDO Regulator with compact package and low dropout characteristics
 Small current LDO regulator

Action Camera Detail of camera motion unit

Camera motion unit



Criteria for device selection

- Lower capacitance ESD protection device is required not to affect the transmission of high speed signals on data lines.

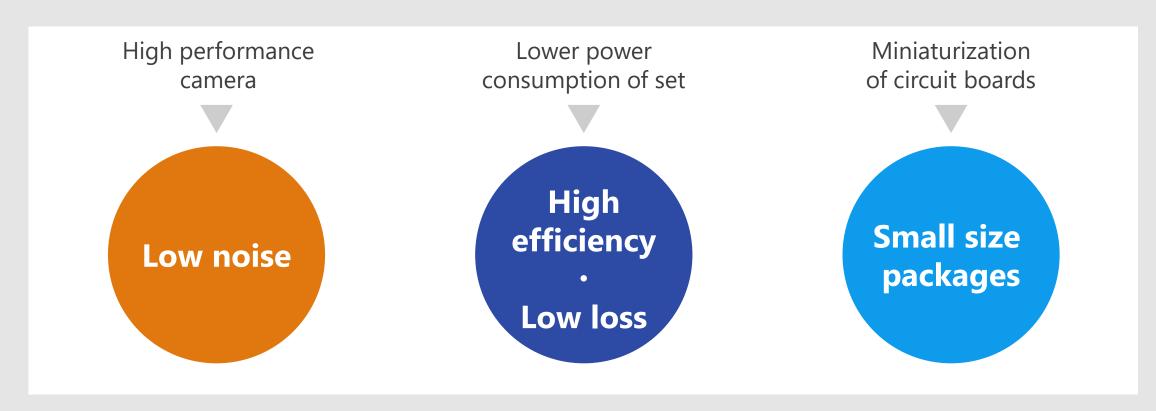
- TVS diode with compact package and high ESD tolerance
 - Standard capacitance TVS diode
- TVS diode with compact package and low capacitance
 - Low capacitance TVS diode



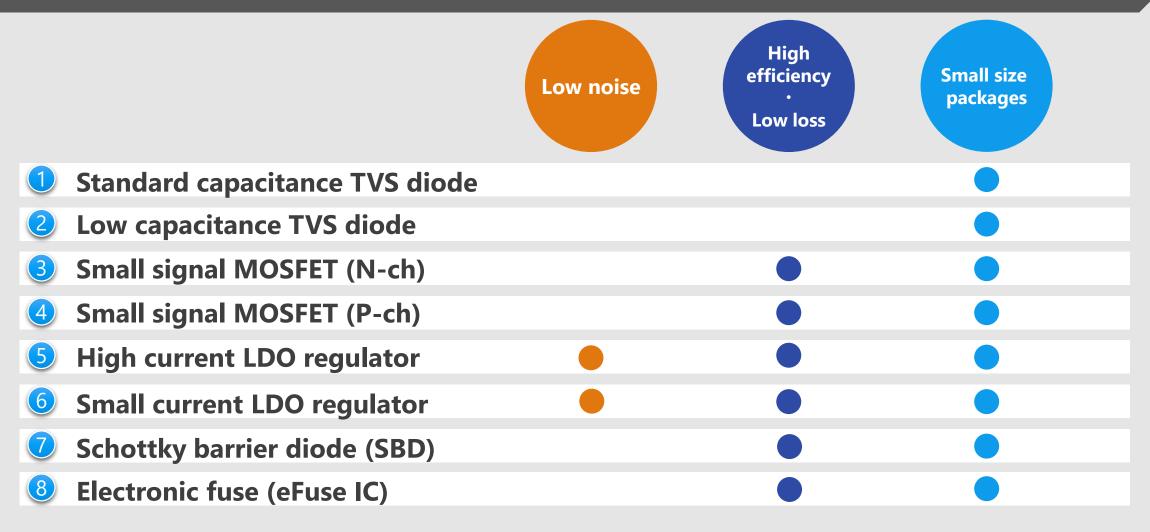


Device solutions to address customer needs

As described above, in the design of action camera, "High performance camera", "Lower power consumption of set" and "Miniaturization of circuit boards" are important factors. Toshiba's proposals are based on these three solution perspectives.



Device solutions to address customer needs



Standard capacitance TVS diodeDF2B7ASL / DF2S14P1CT







Value provided

TVS diode absorbs static electricity (ESD) and surge from external terminals and is suitable for preventing circuit malfunction and device protection.

High ESD pulse absorption performance

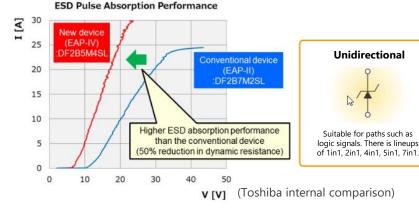
For some products, both low operating resistance and low capacitance are realized, and ensures high signal protection performance and signal quality.

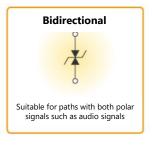
2 Suppress ESD energy by low clamp voltage

TVS diodes steadily protect connected circuits/devices by adopting proprietary technology.

Suitable for high-density mounting

A variety of compact packages are available.





Line up						
Part number	DF2B7ASL	DF2S14P1CT				
Package	SL2	CST2				
V _{ESD} (Max) [kV]	±30	±30				
V _{RWM} (Max) [V]	5.5	12.6				
C _t (Typ.) [pF]	8.5	40				
R _{DYN} (Typ.) [Ω]	0.2	0.5				

(NOTE): This product is designed for ESD protection purpose and cannot be used for purposes other than ESD protection.







This TVS diode has low capacitance that does not affect the transmission of high speed signals on data lines, and is suitable for preventing circuit malfunctions and protecting devices.

High ESD pulse absorption performance

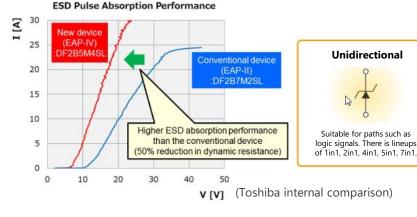
For some products, both low operating resistance and low capacitance are realized, and ensures high signal protection performance and signal quality.

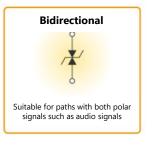
2 Suppress ESD energy by low clamp voltage

TVS diodes steadily protect connected circuits/devices by adopting proprietary technology.

Suitable for high-density mounting

A variety of compact packages are available.





Line up					
Part number	DF2B5M4ASL	DF2B6M4ASL	DF2B6M4SL		
Package	SL2	SL2	SL2		
V _{ESD} (Max) [kV]	±16	±15	±20		
V _{RWM} (Max) [V]	3.6	5.5	5.5		
C _t (Typ.) [pF]	0.15	0.15	0.2		
R _{DYN} (Typ.) [Ω]	0.7	0.7	0.5		

(NOTE): This product is designed for ESD protection purpose and cannot be used for purposes other than ESD protection.







It is suitable for power management switches, etc., and greatly contributes to miniaturization of sets.

Low voltage drive

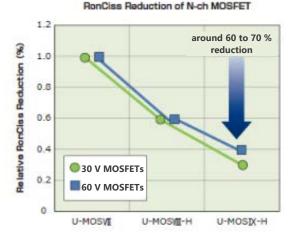
Drive at $V_{DS} = 4.5 \text{ V}$.

Description Low on-resistance

By reducing on-resistance between the drain and source, heat generation and power consumption can be kept low.

3 Compact package

Sealed in SOT-1220 (2.0 x 2.0 mm) package.



(Note: Toshiba internal comparison)

Line up						
Part number		SSM6K513NU	SSM6N55NU			
Package		UDFN6B	UDFN6B			
V _{DSS} [V] I _D [A]		30	30			
		15	4			
$R_{DS(\Omega N)}$ [m Ω]	Тур.	8.0	48			
$R_{DS(ON)} [m\Omega]$ $@V_{GS} = 4.5 \text{ V}$	Max	12	64			
Polarity		N-ch	N-ch x 2			







It is suitable for power management switches, etc., and greatly contributes to miniaturization of sets.

Low voltage drive

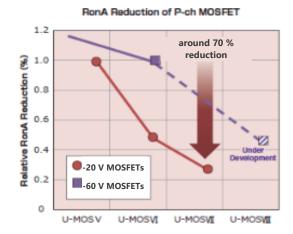
Drive at $V_{DS} = 4.5 \text{ V}$.

Description Low on-resistance

By reducing on-resistance between the drain and source, heat generation and power consumption can be kept low.

3 Compact package

Sealed in SOT-1220 (2.0 x 2.0 mm) package.



(Note: Toshiba internal comparison)

Line up				
Part number		SSM6J507NU		
Package		UDFN6B		
V _{DSS} (Max) [V]		-30		
I _D (Max) [A]		-10		
$R_{DS(\Omega N)}$ [m Ω]	Тур.	19		
$R_{DS(ON)} [m\Omega]$ $@V_{GS} = -4.5 V$	Max	28		
Polarity		P-ch		







This LDO eliminates the switching noise generated in the power supply circuit and provides a power supply with less output voltage fluctuation.

High PSRR

Our LDO regulator has high PSRR (Power Supply Rejection Ratio) characteristic. Stable power supply is realized by removing switching noise generated in the circuit.

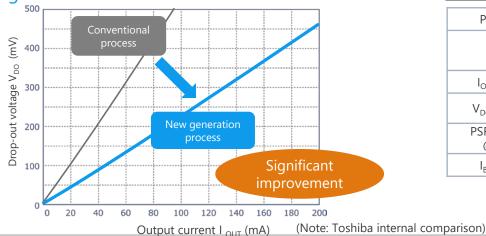
2 Low loss (low dropout)

The heat generated by the circuit can be minimized since our LDO regulator minimizes the losses generated by the circuit.

Suitable for high-density mounting

A variety of compact packages are available.

Low dropout voltage



Line up			
Part number	TCR15AG Series	TCR5BM Series	TCR5RG Series
Package	WCSP6F 🚓	DFN5B	WCSP4F
I _{OUT} (Max) [A]	I _{OUT} (Max) [A] 1.5 V _{DO} (Typ.) [mV] 120 @I _{OUT} = 1.5 A		0.5
V _{DO} (Typ.) [mV]			150 @I _{OUT} = 500 mA
PSRR (Typ.) [dB] @f = 1 kHz		@I _{OUT} = 500 mA 98	100
I _B (Typ.) [μA]	25	19	7







This LDO eliminates the switching noise generated in the power supply circuit and provides a power supply with less output voltage fluctuation.

High PSRR

Our LDO regulator has high PSRR (Power Supply Rejection Ratio) characteristic. Stable power supply is realized by removing switching noise generated in the circuit.

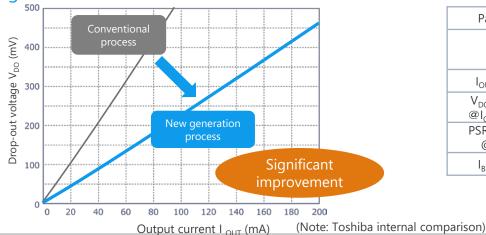
2 Low loss (low dropout)

The heat generated by the circuit can be minimized since our LDO regulator minimizes the losses generated by the circuit.

Suitable for high-density mounting

A variety of compact packages are available.

Low dropout voltage



Line up				
Part number	TCR3RM Series	TCR3UM Series	TCR3UG Series	TCR3DG Series
Package	DFN4C 🔷	DFN4	WCSP4F	WCSP4E
I _{OUT} (Max) [A]	0.3	0.3	0.3	0.3
V _{DO} (Typ.) [mV] @I _{OUT} = 300 mA	98	196	140	195
PSRR (Typ.) [dB] @f = 1 kHz	100	70	70	70
I _B (Typ.) [μΑ]	7	0.34	0.34	65







low V_F and low I_R characteristics were realized and contributes to improved circuitefficiency.

Low V_F characteristics

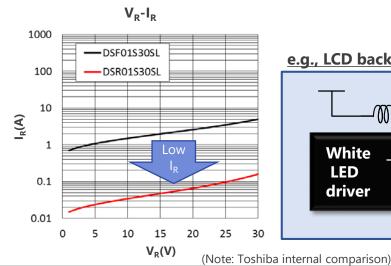
Low V_F characteristics compared to our conventional products was realized. When used in backflow prevention applications, the circuit efficiency can be further improved.

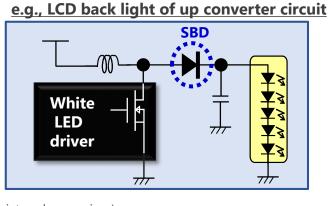
Description Low I_R characteristics

Low I_R characteristics compared to conventional products was realized. When used in backflow prevention applications, the circuit efficiency can be further improved.

Suitable for high-density mounting

A variety of compact packages are available.





Line up					
Part number	DSR01S30SL	CLS10F40			
Package	SL2	CL2E			
V _R (Max) [V]	30	40			
I _O (Max) [A]	0.1	1			
V _F (Max) [V]	0.62 @I _F = 0.1 A	0.57 @I _F = 1 A			
I _R (Max) [μA]	0.7 @V _R = 30 V	25 @V _R = 40 V			







Electronic fuse (eFuse IC) can be used repeatedly to protect circuits from abnormal conditions such as overcurrent and overvoltage.

Can be used repeatedly

When overcurrent flows through the electronic fuse (eFuse IC), the internal detection circuit operates and switches off the internal MOSFET. It is not destroyed by a single overcurrent and can be used repeatedly.

TEC62368-1 certified

Toshiba's eFuse ICs are certified to the international safety standard IEC62368-1 (G9: Integrated circuit (IC) current limiters) and contribute to robust protection and simplification of circuit design.

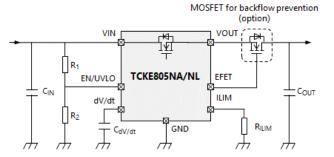
Note: TCKE712BNL is scheduled to be certified in Sep. 2021.

Rich protection functions

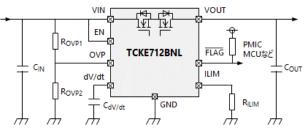
TCKE8 Series: short-circuit protection, overcurrent protection, overcurrent clamp function, overvoltage clamp function, thermal shut down, inrush current suppression, backflow prevention (optional), etc.

TCKE7 Series: short-circuit protection, overcurrent protection, overvoltage protection, thermal shut down, FLAG signal output, backflow prevention (built-in), etc.

Reference circuit example of TCKE8 Series



Reference circuit example of TCKE7 Series



Line up

спіс ар				
Part number	TCKE800NA/NL	TCKE805NA/NL	TCKE812NA/NL	TCKE712BNL
Package	WSON10B 3.0 x 3.0 x 0.75 mm			WSON10 3.0 x 3.0 x 0.75 mm
V _{IN} [V]		4.4 to 18 28		
R_{ON} (Typ.) [m Ω]				
Return function	NL: Latch	Latch type (external signal control)		
V _{OVC} (Typ.) [V]	-	Adjustable		

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